# NSN 5961-01-212-8006

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## **Inclosure Material:**

Metal

**Overall Length:** 

0.180 inches

# **Terminal Length:**

0.500 inches

# **Overall Diameter:**

0.370 inches

#### **Internal Configuration:**

Field effect

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-39

#### **Mounting Method:**

Terminal

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 20.0 gate to source voltage

## **Current Rating Per Characteristic:**

8.00 amperes drain current

# Power Rating Per Characteristic:

25.0 watts total power dissipation

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

## **Test Data Document:**

78711-t235a372 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## **Terminal Type And Quantity:**

3 uninsulated wire lead

#### Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

## Fiig:

A110a0